

28F010 1024K (128K X 8) CMOS FLASH MEMORY

Manufacturers

[Intel Corp](#)

Package/Case

DIP-32

Product Type

Embedded Processors & Controllers

RoHS

Lifecycle



Images are for reference only

Please submit RFQ for TP28F010-120 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

TP28F010-120 is a 1-megabit (128K x 8) flash memory device manufactured by the company Toshiba. Here are some of its features:

Features

Operating voltage: 5V

Access time: 120 nanoseconds

Organization: 128K x 8 bits

Endurance: 100,000 program/erase cycles

Data retention: 20 years

Erase time: sector/chip erase in 10ms/15ms

Package type: 32-pin plastic DIP or PLCC



Related Products



[RTPXA270C5C312](#)

Intel Corp
PBGA-356P



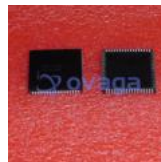
[EN87C196KC20](#)

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[KU80386EX25](#)

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[AN87C196KT](#)

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[QU80C186EC20](#)

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[N80C251SB16](#)

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